GTM

CORPORATION

ISSUED DATE :2004/11/18 REVISED DATE :

G494SD

SURFACE MOUNT, SCHOTTKY BARRIER DIODE VOLTAGE 40V, CURRENT 0.4A

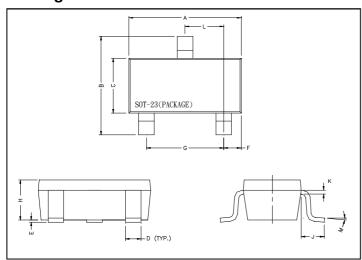
Description

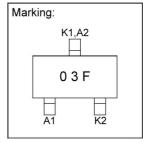
The G494SD is designed for low power rectification.

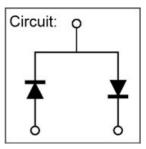
Feature

- Two diode with serial
- High reliability.

Package Dimensions







REF.	Millimeter		REF.	Millimeter	
	Min.	Max.	ILI.	Min.	Max.
Α	2.70	3.10	G	1.90 REF.	
В	2.40	2.80	Н	1.00	1.30
O	1.40	1.60	K	0.10	0.20
D	0.35	0.50	J	0.40	1
Е	0	0.10	Ĺ	0.85	1.15
F	0.45	0.55	М	0°	10°

Absolute Maximum Ratings at Ta = 25℃

Parameter	Symbol	Ratings	Unit
Junction Temperature	Tj	+125	$^{\circ}\mathbb{C}$
Storage Temperature	Tstg	-40 ~ +125	$^{\circ}\mathbb{C}$
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	40	V
Maximum RMS Voltage	V_{RMS}	28	V
Maximum DC Blocking Voltage	V_{DC}	25	V
Peak Forward Surge Current at 8.3mSec single half sine-wave	I _{FSM}	2.0	Α
Typical Junction Capacitance between Terminal(Note1)	CJ	20	pF
Maximum Average Forward Rectified Current	lo	0.4	Α
Total Power Dissipation	PD	225	mW

Electrical Characteristics (At Ta = 25°C unless otherwise noted)

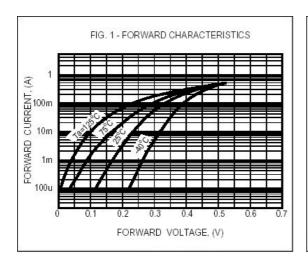
Characteristics	Symbol	Max.	Unit	Test Condition
Maximum Instantaneous Forward Voltage	V _F (1)	0.3	٧	IF(1) = 10mA
Maximum Instantaneous Forward Voltage	V _F (2)	0.5	V	IF(2) = 200mA
Maximum Average Reverse Current	IR	70	uA	VR = 25V

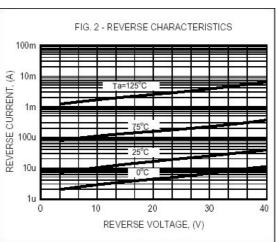
Notes: 1. Measured at 1.0MHz and applied reverse voltage of 10.0 volts.

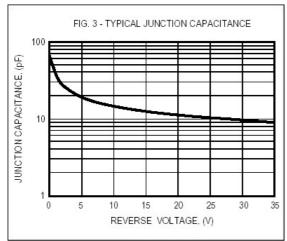
2. ESD sensitive product handling required.

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Characteristics Curve







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